

High-Current Avalanche-Tunneling And
Injection-Tunneling Semiconductor
Diode-to-Metal Stable Cold Emitter ...
Vladimir V. OSEPOV et al.
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Exhibit
A →

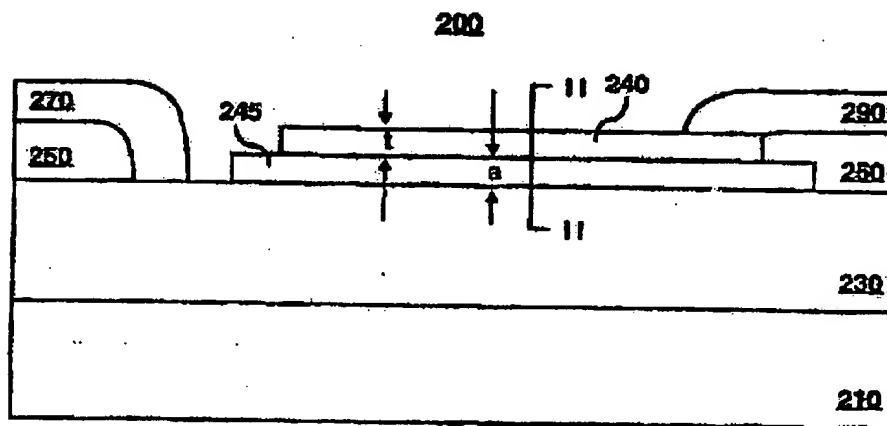


FIG 2A

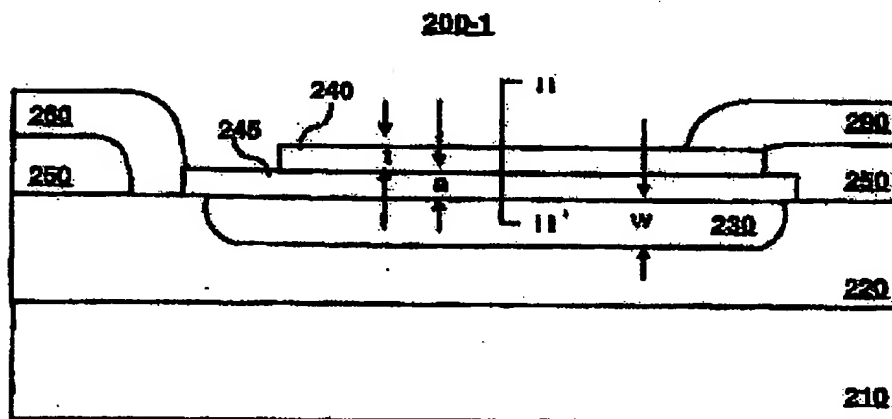


FIG 2B

U.S. Patent

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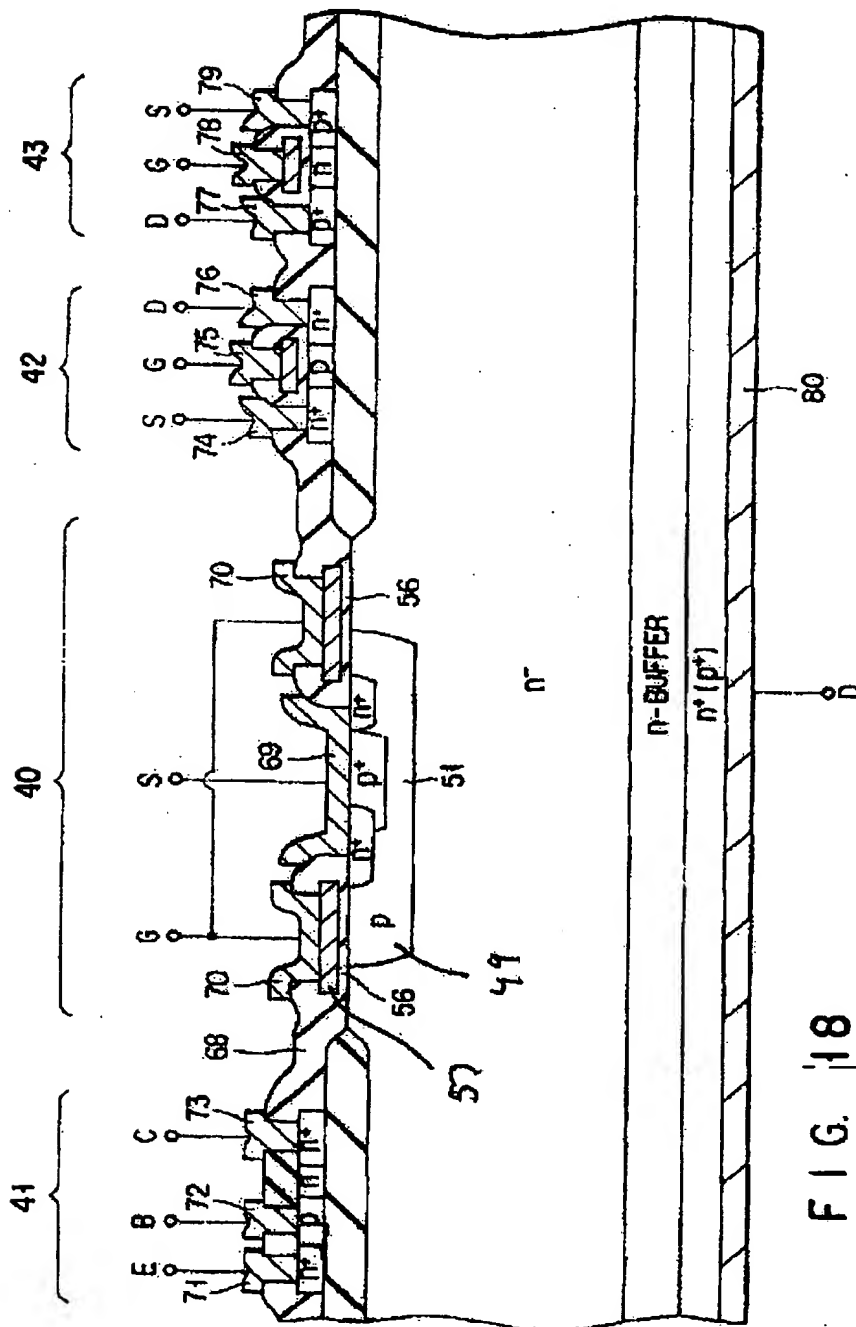


FIG. 18

Exhibit B